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ERC Advanced Grant MeQuaNo

Edge Magnetoplasmons in Graphene ANK in the Quantum Hall Regime D. C. Glattli CEA Saclay , France

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electronflying qubits (levitons), electron interferometer, quantum shot noise, electron quantum state tomography Graphene.,

Plasmons and/in Graphene

fast rising field

Koppens, F.H.L., Chang, D.E. and de Abajo, F.J.G. Nano Letters 11, 3370-3377 (2011). Fei, Z. et al. Infrared nanoscopy of Dirac plasmons at the graphene-SiO2 interface. Nano Lett. 11, 4701-4705 (2011).

Ju, L. et al. Graphene plasmonics for tunable terahertz metamaterials. Nature Nanotechnol. 6, 630-634 (2011).

Chen, J. et al. Optical nano-imaging of gate-tunable graphene plasmons. Nature 487 77-81 (2012).

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Ryzhii V. Terahertz plasma waves in gated graphene heterostructures. Jpn. J. Appl. Phys. 45, L923–L925 (2006)

Edge vs bulk plasmons

 $\mathsf{BULK} \\ \omega \sim n^{1/4} \sim V_G^{1/4}$

non chiral

weak gate dependence

damped < inverse relaxation time (~THz) THz to Infrared domain EDGE $\omega \sim n \sim V_G$

chiral

reversible with gate or field

weakly damped on Hall plateaus GHz to THz domain

possibility of chiral plasmonics (gated rf-isolators, circulators,...)





bulk

boundary

Edge magneto-plasmons applications

PHYSICAL REVIEW X 4, 021019 (2014)

Hall Effect Gyrators and Circulators

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> possibility of chiral plasmonics (gated rf-isolators, circulators,...)

 $S = \left(\begin{array}{ccc} 0 & 0 & 1 \\ 1 & 0 & 0 \\ 0 & 1 & 0 \end{array} \right).$





FIG. 15. An exploded view of a sandwich structure, based on the capabilities recently reported in [62]. A graphene flake is encapsulated between two layers of insulating boron nitride (BN). Four edge electrodes grown above the structure as shown could serve as the four capacitive contacts of the two-port gyrator. Graphene: B = 2 Tesla, T=300K

 $\mu \sim 10^4 \, V \, cm^{-2} \, s^{-1}$

Hall angle > 45°

enough for low loss circulator

dynamics mediated by Edge Magneto-plasmons

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2D plasmons





2D magneto-plasmons



2D magneto-plasmons



Edge Magneto-Plasmons (EMP)





D. C. Glattli, E. Y. Andrei, G. Deville, J. Poitrenaud, and F. I. B. Williams Service de Physique du Solide et de Résonance Magnétique, Centre d'Etudes Nucléaires de Saclay, F-91191 Gif-sur-Yvette Cedex, France (Received 16 January 1985)

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 \rightarrow combines with QHE edge channels

Edge Magneto-Plasmons (EMP) in the Quantum Hall Regime



E.Y. Andrei, D.C. Glattli, F. Williams and M. Heiblum Surf. Sci. 196 501-506 (1998)

 $\mathbf{B}_{\mathcal{Z}}$



E.Y. Andrei, D.C. Glattli, F. Williams and M. Heiblum Surf. Sci. 196 501-506 (1998)



Edge Magneto-Plasmons (EMP) in the Quantum Hall Regime

complete expression :

$$\omega_{EMP} = \frac{\sigma_{Hall}}{2\pi\varepsilon_0\varepsilon_{eff}} q \left(\log\frac{2}{|q|w} + 1\right) + v_D q$$

 $\ensuremath{\mathcal{W}}$: cutt-off length with respect to sharp edge

Damping extremely low compare with bulk plasmons

THEORY WORK:

Fetter, A. L., Edge magnetoplasmons in a bounded two-dimensional electron fluid.

Phys. Rev.B 32, 7676-7684 (1985).

Volkov, V. A. and Mikhailov, S. A. Theory of edge magnetoplasmons in a two-dimensional electron gas. JETP Lett. 42, 556-560 (1985).

Volkov, V. A., Galchenkov, D. V., Galchenkov, L. A., Grodnenskii, I. M., Matov, O. R. and

Mikhailov, S. A. Edge magnetoplasmons under conditions of the quantum Hall effect.

JETP Lett. 44, 655-659 (1986).

Volkov, V. A. and Mikhailov, S. A. Edge magnetoplasmons: low-frequency weakly damped excitations in inhomogeneous two-dimensional electron systems.

Sov. Phys. JETP 67, 1639-1653 (1988).

also - L. Glazman

- Allan McDonald All theory work addressed conventional 2DEG in QHE regime



Edge Magneto-Plasmons (EMP) in the Quantum Hall Regime

complete expression :

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EMP EXPERIMENTAL WORKs: Allen, S. J., Stormer, H. L. and Hwang, J. C. M. Phys. Rev. B 28, 4875-4877 (1983). Andrei, E. Y., Glattli, D. C., Williams, F. I. B. and Heiblum M. Surf. Science 196, 501-506 (1988). Ashoori, R. C., Stormer, H. L., Pfeiffer, L. N., Baldwin, K. W. and West, K. Phys. Rev. B 45, 3894-3897 (1992). Zhitenev, N. B., Haug, R. J., Klitzing, K. v. and Eberl, K. Phys. Rev. Lett. 71, 2292-2295 (1993). Ernst G., Haug, R. J., Kuhl, J., von Klitzing, K. v. and Eberl, K.. Phys. Rev. Lett. 77, 4245-4248 (1996). Kumada, N., Kamata, H. and Fujisawa, T. All works on GaAs/GaAlAs 2DEG in QHE Phys. Rev. B 84, 045314 (2011) regime



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Quantum Hall Effect in Graphene



QHE Edge States in Graphene

• edges state drift velocity :

$$v_{drift} = \frac{E}{B} \approx \frac{\hbar v_F / {l_c}^2}{e B}$$
$$v_{drift} \approx v_F = 10^6 \text{ m.s}^{-1}$$

example : v = 6 in the bulk

$$G_{Landauer} = 3 \times \frac{2e^2}{h} = \sigma_{Hall}$$

- •Hall conductance agrees with Landauer picture
- valley degeneracy may be lifted at the edge Brey, L. and Fertig, H. A.. Phys. Rev. B 73, 195408 (2006). Dmitry A. Abanin, Patrick A. Lee, and Leonid S. Levitov Phys. Rev. Lett. 96, 176803 (2006) Delplace P. and Montambaux, G. Phys. Rev. B 82, 205412 (2010).



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 Delplace P. and Montambaux, G. Phys. Rev. B 82, 205412 (2010).



CHIRAL QHE Edge States in Graphene



K. Bennaceur, D. C. G. (2007) SPEC, CEA Saclay

80 100

CHIRAL QHE Edge States in Graphene



K. Bennaceur, D. C. G. (2007) SPEC, CEA Saclay



CVD Graph. transf. on SiO2

absorption

Crassee, I., Orlita, M., Potemski, M., Walter, A. L., Ostler, M., Seyller, Th., Gaponenko, I., Chen, J. and Kuzmenko, A. B. "Intrinsic Terahertz Plasmons and Magnetoplasmons in Large Scale Monolayer Graphene, "Nano Letters 12, 2470 (2012).

Yan, H., Li, Z., Li, X., Zhu, W., Avouris, P. and Xia, F. "Infrared Spectroscopy of Tunable Dirac Terahertz Magneto-Plasmons in Graphene" Nano Lett. 2012, 12, 3766-3771

NO QUANTUM HALL REGIME CHIRALITY remained to be SHOWN DRIFT VELOCITY not MEASURED

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Sample Fabrication

Exfoliated Graphene (natural graphite)

30X30 um² flake pattern as ellipsoidal shape by nanolithography

sample photo







Experimental setup



Modulated transmission as function of field



Petkovic, F. I. B. Williams, K. Bennaceur, F. Portier, P. Roche, and D. C. Glattli, Phys. Rev. Lett 110, 016801 (2013)

Propagation time vs field



Petkovic, F. I. B. Williams, K. Bennaceur, F. Portier, P. Roche, and D. C. Glattli, Phys. Rev. Lett 110, 016801 (2013)



ARTICLE

3

2

0

0

2

4

6

8

filling factor v

10

12

 v_{emp} (10⁸ cms⁻¹)

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Plasmon transport in graphene investigated by time-resolved electrical measurements

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10,016801 (2013)

epitaxial graphene on 0001 SiC



Carrier Drift Velocity and Edge Magnetoplasmons in Graphene

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Intrinsic and extrinsic decay of edge magnetoplasmons in graphene

N. Kumada,^{1,2,*} P. Roulleau,² B. Roche,² M. Hashisaka,³ H. Hibino,¹ I. Petković,² and D. C. Glattli²

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(to appear in Phys. Rev. Lett.)



time domain measurents

Graphene on SiC (from NTT Atsugi Jpn)

larger size : 1mm and 200µm perimeter

dc- 50GHz CEA Saclay microwave set-up



mobility ~ 10 000 cm² V⁻¹s⁻¹ density $\sim 6 \ 10^{11} \text{ cm}^{-2}$

Intrinsic and extrinsic decay of edge magnetoplasmons in graphene

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(N. Kumada et al., PRL 113, 266601 (2014)

frequency domain measurements :



Intrinsic and extrinsic decay of edge magnetoplasmons in graphene

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(Dated: June 27, 2014)

(N. Kumada et al., PRL 113, 266601 (2014)

frequency domain measurements :



 V_D = 0.5 ±0.1 10⁸ cm/s (consistent with 0.7±0.1 10⁸ found by I. Petkovic PRL 2013) w ≈ 4 nm (much smaller than in GaAs/GaAlAs ≈ 500 nm)

time domain measurements :

(N. Kumada et al., PRL 113, 266601 (2014)



time domain measurements :



(N. Kumada et al., PRL 113, 266601 (2014)





EMP damping arises from

 capacitive coupling to localized edge states in the bulk (low temperature)

 $\frac{1}{\tau} = \alpha f^2 + \beta(T)$

- finite longitudinal resistance (high >20K temperature)



EMP damping arises from

 capacitive coupling to localized edge states in the bulk (low temperature) $\frac{1}{\tau} = \alpha f^2 + \beta(T)$

- finite longitudinal resistance (high >20K temperature)

analysis of data give α constant and : $\beta(T) \propto \exp(-(T_0/T)^{1/2})$

consistent with Efros-Shklovskii Var. Range Hopping with $T_0 \sim 730K$ also consistent with tranport measurements of To ~ 900 K in graphene see *K. Bennaceur et al. Phys. Rev. B 86, 085433 (2012).*



EMP damping arises from

- capacitive coupling to localized edge states in the bulk (low temperature)
- finite longitudinal resistance (high >20K temperature)

Typical EMP resonance quality factor:

Q= 15 @ 1.7 GHz and Q=8.5 @ 7.6 GHz (at T=4.2°K)

Conclusion & Perspectives

- existence of EMP in graphene in QH regime
- chiral propagation
- provide first exp. estimation of drift velocity ~(0.7 +/-0.2) 10⁶m/s
- full check of EMP dispersion relation
- EMP lifetime measurement and identification of damping mechanism
- very high Q at GHz frequency



possibility of chiral plasmonics (gated rf-isolators, circulators,...)





ERC Advanced Grant MeQuaNo



ADMENNATIONALE DE LA RIOGEDOF

Chiral Plasmonics in Graphene THANKS TO :

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D. C. Glattli (CEA Saclay)

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Why there is no echo



reciprocity

modulation much more efficient on one side - one ohmic and one capacitive contact

model:



no echo is expected

(D. C. Glattli et al., supplementary material, arXiv:1206.2940 (2012)



Figure 1 | Graphene on SiC and the experimental techniques. (a) Atomic force microscopy phase image of graphene on SiC (ref. 27). Scale bar, 1 µm. Single-layer graphene (brown colour in majority regions) covers the substrate, while two or more graphene layers (yellow colour in minority regions) are formed along the terrace edge. As few-layer graphene regions are fragmented, the single-layer graphene dominates carrier transport. (b) R_{xx} and R_{xy} at 1.5 K of a Hall bar device with the channel width and length of 0.2 and 1.1 mm, respectively. The mobility is 12,000 cm² V⁻¹ s⁻¹. (c) Schematic illustration (not to scale) of the sample structure and the experimental setup for the time-resolved transport measurement.